

Rectifier diode

SMA 1000 V



For surface mount applications

Low profile package

Glass passivated chip junction

SPECIFICATION:

Peak off-state voltage	1000 V
Forward current	1.0 A
Recovery time	75 ns
Housing type	SMA
Configuration	Single
Operating temperature	-55...+150 °C
Conducting-state voltage	1.65 V
Off-state current	5 μ A



Art. Nr.

RND US1M-AT

